

2SC3052

FOR LOW FREQUENCY AMPLIFY APPLICATION
SILICON NPN EPITAXIAL TYPE

DESCRIPTION

2SC3052 is a mini package resin sealed silicon NPN epitaxial transistor, It is designed for low frequency voltage application.

FEATURE

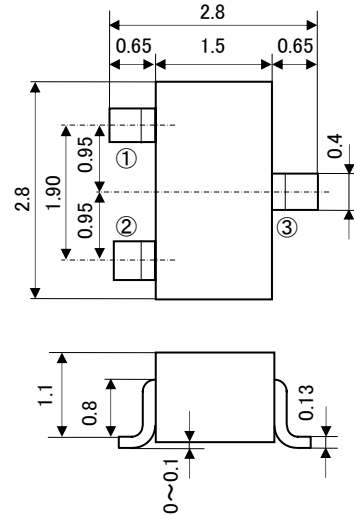
- Small collector to emitter saturation voltage.
VCE(sat)=0.3V max (@IC=100mA/IB=10mA)
- Excellent linearity of DC forward current gain.
- Super mini package for easy mounting

APPLICATION

For Hybrid IC, Small type machine low frequency voltage amplify application.

OUTLINE DRAWING

Unit: mm



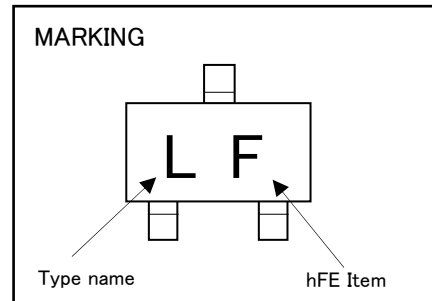
TERMINAL CONNECTER

- ①: BASE JEITA: SC-59
- ②: EMITTER JEDEC: Similar to TO-236
- ③: COLLECTOR

MAXIMUM RATINGS (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base voltage	V _{CB0}	50	V
Emitter to Base voltage	V _{EB0}	6	V
Collector to Emitter voltage	V _{CE0}	50	V
Collector current	I _O	200	mA
Collector dissipation	P _c	200	mW
Junction temperature	T _j	+150	°C
Storage temperature	T _{stg}	-55~+150	°C

MARKING



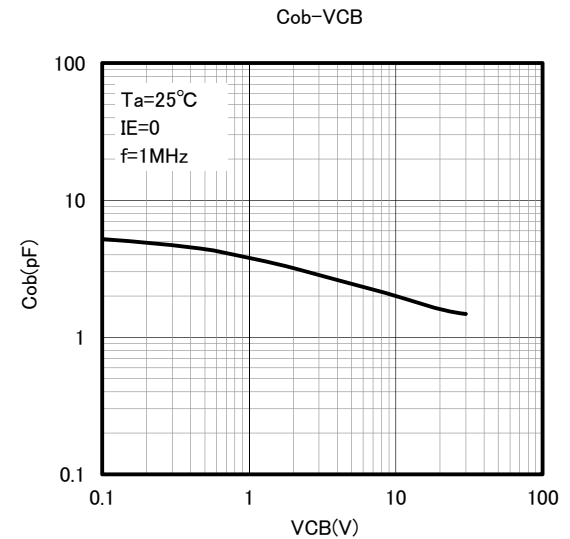
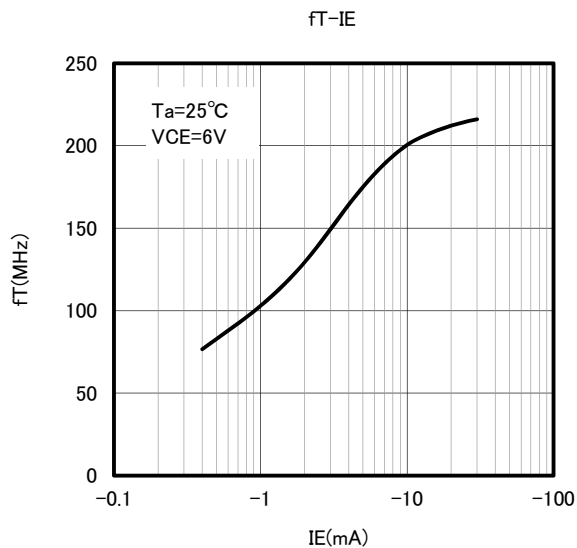
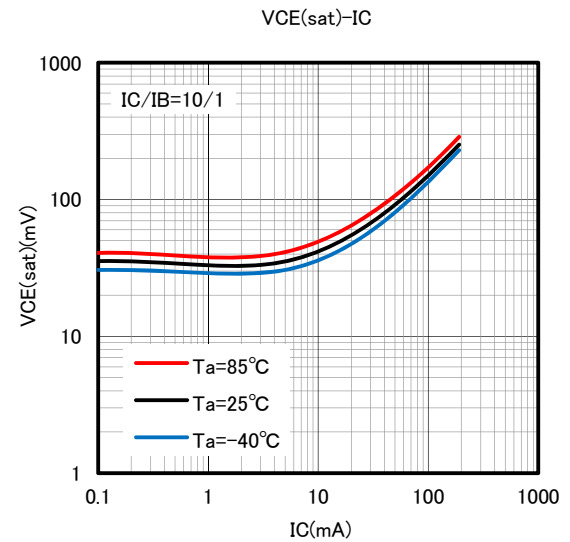
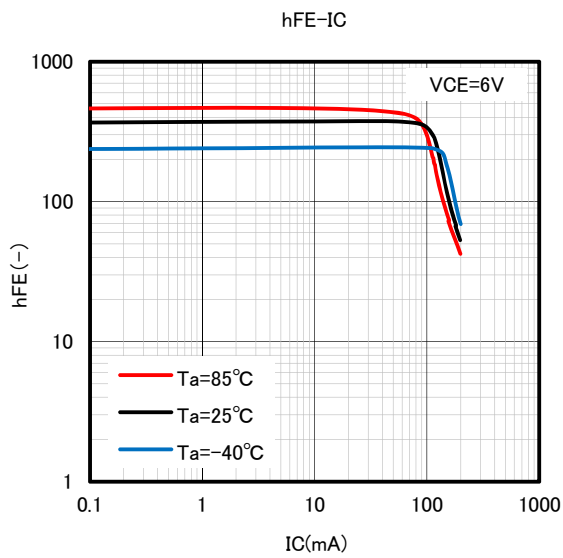
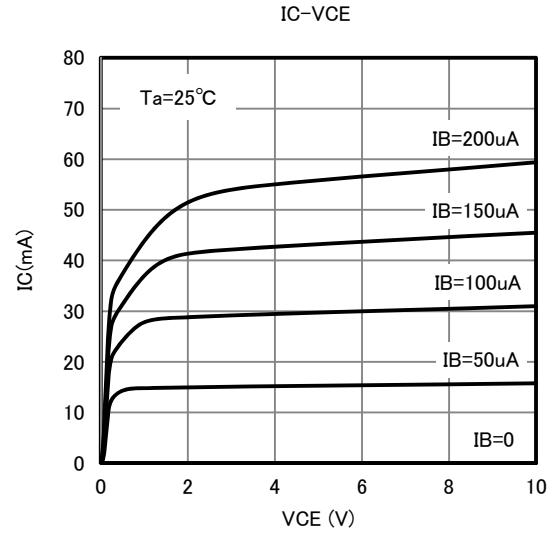
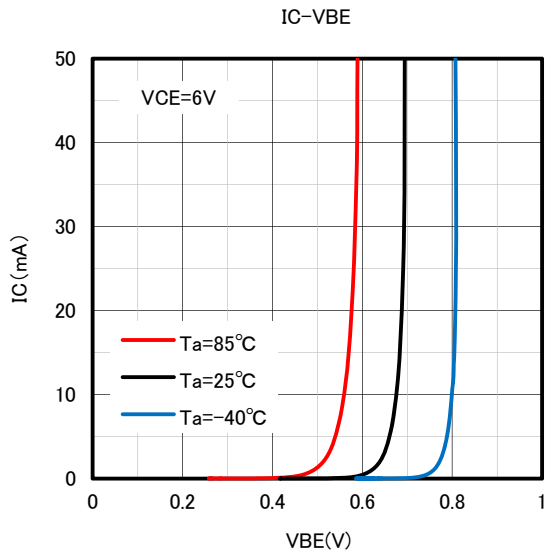
ELECTRICAL CHARACTERISTICS (Ta=25°C)

Parameter	Symbol	Test conditions	Limits			Unit
			Min	Typ	Max	
C to E breakdown voltage	V(BR) _{CEO}	I _C =100μA, R _{BE} =∞	50	-	-	V
Collector cut off current	ICBO	V _{CB} =50V, I _E =0mA	-	-	0.1	μA
Emitter cut off current	IEBO	V _{EB} =6V, I _C =0mA	-	-	0.1	μA
DC forward current gain ※	hFE	V _{CE} =6V, I _C =1mA	150	-	500	-
DC forward current gain	hFE	V _{CE} =6V, I _C =0.1mA	100	-	-	-
C to E Saturation voltage	VCE(sat)	I _C =100mA, I _B =10mA	-	-	0.3	V
B to E Saturation voltage	VBE(sat)	I _C =100mA, I _B =10mA	-	-	1.0	V
Gain bandwidth product	fT	V _{CE} =6V, I _E =-10mA	-	200	-	MHz
Collector output capacitance	Cob	V _{CB} =6V, I _E =0, f=1MHz	-	2.5	-	pF
Noise figure	NF	V _{CE} =6V, I _E =-0.1mA, f=1kHz, RG=2kΩ	-	-	15	dB

※) It shows hFE classification at right table.

Item	E	F
hFE Item	150~300	250~500

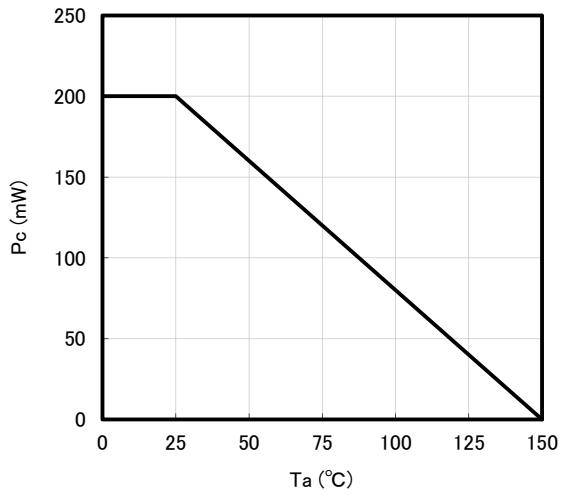
TYPICAL CHARACTERISTICS



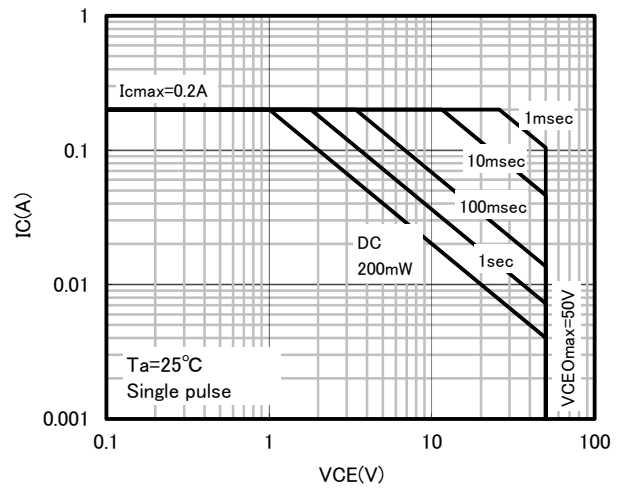
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SILICON NPN EPITAXIAL TYPE

Pc-Ta



ASO



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